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First principles study on the structural stability, mechanical stability and optoelectronic properties of alkali-based single halide perovskite compounds XMgI_3 ($\text{X} = \text{Li}/\text{Na}$): DFT insight

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Metal-halide perovskites are recognized as cutting-edge solar energy technology, boasting remarkable absorption capabilities, minimal environmental impact, and cost-effectiveness. This study delves into the structural stability, mechanical stability, and optoelectronic properties of lead-free halide perovskites, specifically XMgI_3 ($\text{X} = \text{Li}/\text{Na}$), by utilizing the CASTEP and WIEN2k software along with the GGA-PBE and Tran–Blaha modified Becke–Johnson (TB-mBJ) exchange–correlation functions to compare their electronic properties. The structural and mechanical stabilities were confirmed by assessing their tolerance factor and formation energy and by evaluating their elastic constants, respectively. Using the TB-mBJ exchange–correlation potential function, the calculated indirect band gap values for LiMgI_3 and NaMgI_3 were 2.474 and 2.556 eV, respectively. These band gaps are suitable for solar energy harvesting due to their broad optical absorption ranging from infrared to visible light. The partial density of states and the total density of states were determined to investigate the contribution of individual atoms. Consequently, this study can guide researchers focusing on the experimental synthesis of these materials at the laboratory scale for in-depth exploration, particularly in applications such as photovoltaics and various optoelectronic devices.

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1. Introduction

With the increase in the world's population and economy, the demand for energy is growing.¹ However, non-renewable energy sources such as fossil fuels employed to meet this demand are being depleted,^{2,3} and the energy generated from non-renewable energy sources is harmful to the surrounding environment due to CO_2 emissions.⁴ Therefore, it is necessary to discover safe and reliable new energy technologies. To solve this kind of problem, perovskite materials (ABX_3)⁵ have the characteristics of photovoltaics (PV), the most common type of solar technology,^{6,7} due to their significant properties^{6,8–10} that contribute to the production of clean energy from pollution.^{11–13} The most promising solar energy in recent years has been organic–inorganic halide perovskite (OIHP)-based PV technology, which is efficient, inexpensive, and has special optoelectronic effects.

However, the low stability of OIHPs hinders their application in the production of solar cells. For example, conventional OIHPs such as MAPbI_3 (ref. 14) and MAPbX_3 ($\text{X} = \text{Cl}$, Br , and I)¹⁵ have attracted considerable interest due to their high efficiency and suitability for optoelectronic applications, despite concerns regarding their instability and the toxicity associated with the presence of lead (Pb). Most of the metal halide Pb-free materials such as ZYbI_3 ($\text{Z} = \text{Rb}$, Cs) have been used as perovskite materials as a result of their high efficiency.¹⁶ Mahmood *et al.*¹⁶ reported the preparation of RbYbI_3 and CsYbI_3 with a narrow direct band of 1.22 eV and 1.12 eV, respectively, which are considered suitable for the fabrication of solar cells.

Interestingly, Ray *et al.*¹⁷ proposed substituting divalent atoms (such as Ge , Sn , Pb , Mg , Ca , Sr , and Ba) for Pb to address the toxicity concerns associated with perovskite materials in photovoltaic applications. They found that Mg and Ba perovskites are unlikely to form in the cubic, tetragonal, and orthorhombic phases due to their positive formation energies. Alternatively, Ca and Sr perovskites exhibit negative formation energies with respect to the metal-iodide precursors and they possess wide band gaps, making them less favorable candidates for use in photovoltaic devices. They additionally reported that the predictive capability of a local density functional with a non-separable gradient approximation (NGA) closely resembles that

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of hybrid functionals in terms of band gap predictions, particularly when M in CsMI_3 represents a p-block element such as Pb, Sn, and Ge.

The stability of perovskite materials was identified to be enhanced by introducing K and Rb atoms,^{18–21} specifically KGeX_3 and RbGX_3 (where $X = \text{Cl}$ or Br). Due to their exceptional optoelectronic properties, which include a high static refractive index, low reflectivity, high absorption coefficient, and excellent stability, they have been thoroughly investigated for their possible uses in solar energy and photoelectric systems. Furthermore, they exhibit relatively low levels of toxicity. Additionally, CsGeX_3 ($X = \text{F}$, Cl , and Br) perovskite has been identified as a promising candidate for optoelectronic applications owing to its exceptional electronic, optical, thermoelectric, and tunable band gap properties.^{5,22,23} Lead-free metal halide compounds XBeCl_3 ($X = \text{Ga}/\text{Ag}$)^{24,25} and NaXCl_3 ($X = \text{Be}/\text{Mg}$)²⁶ have been investigated for application in optoelectronic devices due to their unique structural, optical, electronic, and elastic properties. GaBeCl_3 and AgBeCl_3 have band gaps of 3.03 eV and 3.25 eV, while NaBeCl_3 and NaMgCl_3 show band gaps of 4.15 eV and 4.16 eV, respectively. An increase in atomic radii corresponds to a decrease in band gap. These materials also exhibit ductility, enhancing their suitability for use in optoelectronic devices. First-principle calculations were used to comprehensively evaluate these properties.

The electrical and optical properties of different cubic lead-free halide perovskites, CsMgX_3 ($X = \text{Cl}$ and Br) compounds, were studied.²⁷ Similar to these compounds, the cubic halide perovskite CsBX_3 ($B = \text{Sn}$, Ge , $X = \text{I}$, Br , and Cl) compounds were reported to be suitable for optoelectronic energy devices.²⁸ Furthermore, recently narrow band gap perovskite materials such as BaZrS_3 (ref. 6) and CsYbI_3 (ref. 16) were reported. Owing to their narrow band gap, the reported materials are highly recommended for perovskite solar cell applications due to their wide absorption spectrum, primarily covering the visible and infrared regions. However, their elements are categorized as transition metals and lanthanides, which are computationally expensive and result in the formation of compounds with a relatively high density. In the calculation of the electronic structure of transition metals, standard density functional theory (DFT) underestimates the results. Therefore, it is essential to consider additional methods such as incorporating the Hubbard–U function or hybrid function.

Caid *et al.*²⁹ introduced $\text{Cs}_2\text{CdZnCl}_6$, a lead-free halide double perovskite, *via* DFT calculations. This compound exhibits mechanical stability in the cubic nonmagnetic phase and has a direct band gap of 1.43 eV. Its optical conductivity was determined to be up to 13.0 eV, showing a significant ultraviolet photoresponse. These characteristics suggest that $\text{Cs}_2\text{CdZnCl}_6$ is promising for optoelectronic applications, making it a valuable addition to materials science and technology. In another study, Caid *et al.*³⁰ extensively investigated $\text{Cs}_2\text{B}'\text{B}''\text{Br}_6$ double perovskites, revealing their potential in various technological fields. These compounds demonstrated robust stability with negative formation energies and favorable elastic constants. In the case of both BeMg and CdBe , $\text{Cs}_2\text{B}'\text{B}''\text{Br}_6$ exhibited direct band gaps, whereas indirect band gaps were observed with

CdGe , GeMg , GeZn , and MgZn . The optical property assessments highlighted the exceptional dielectric characteristics and strong light absorption in visible and UV spectra of these perovskites, making them promising candidates for solar cells and energy harvesting technologies, indicating significant potential for future energy and optoelectronic advancements.

Therefore, to address these issues, we were motivated to develop transition metal-free and lightweight compounds within alkali and alkaline-based halide perovskite materials (XMgI_3 , $X = \text{Li}/\text{Na}$). Our proposed materials exhibit superior optoelectronic properties compared to previous reports, particularly maintaining a narrow band gap, which enhances the photon absorption region. To the authors' knowledge, there are currently no reports available on alkali metal-based iodide perovskite compounds, namely LiMgI_3 and NaMgI_3 , based on either DFT simulations or experimental studies. Thus, this study aimed to thoroughly investigate the mechanical stability, optoelectronic characteristics, and atomic population analysis of XMgI_3 ($X = \text{Li}/\text{Na}$) using DFT and the CASTEP and WIEN2k software. This article presents XMgI_3 ($X = \text{Li}$ and Na) perovskite compounds as novel and inventive materials for solar cell applications that outperforms all previously investigated metal-halide perovskites.

2. Computational analysis

In this investigation, we applied the plane wave pseudopotential approach utilizing CASTEP software^{31–34} based on DFT principles. The electron exchange–correlation energy was computed following the Perdew–Burke–Ernzerhof (PBE) scheme within the framework of the generalized gradient approximation (GGA).³⁵ We used an ultrasoft pseudopotential³⁶ to describe the atomic potential. The electron configurations of the Li, Na, Mg, and I atoms are $1s^2 2s^1$, $[\text{Ne}] 3s^1$, $[\text{Ne}] 3s^2$, and $[\text{Kr}] 5s^2 4d^{10} 5p^5$, respectively. For optimizing the crystal structure, we employed a plane wave cutoff energy of 700 eV and a $6 \times 6 \times 6$ k -point grid in the Brillouin zone³⁷ for both XMgI_3 ($X = \text{Li}/\text{Na}$) compounds. Structure optimization and lattice parameter calculations were carried out using the BFGS method. The specific tolerances included a total energy of 5.0×10^{-6} eV per atom, self-consistent field (scf) of 5.0×10^{-7} eV per atom, maximum force of $0.01 \text{ eV } \text{\AA}^{-1}$, maximum stress of 0.02 GP, and maximum displacement of 5.0×10^{-4} Å. The elastic constants, electron localization function, and Mulliken population analysis were performed using CASTEP software. The Bader charge analysis was performed using Quantum ESPRESSO.

To precisely assess the ground-state characteristics and optoelectronic properties of the materials, the full-potential linearized augmented plane wave (FP-LAPW)³⁸ method within the WIEN2k code was used.³⁹ The Trans–Blaha (TB-mBJ) exchange–correlation approximations were employed. Implementing the TB-mBJ function yielded a highly accurate band gap value.^{40,41} For the specified objective, the adjusted fundamental parameters were chosen as the standard configuration in the computational software, incorporating $R_{\text{MT}} \times K_{\text{max}} = 8$, with K_{max} denoting the wave vector and R_{MT} representing the muffin-tin sphere radius. A k -mesh of $15 \times 15 \times 15$ was chosen



to ensure precise energy calculations. The self-consistent field method with an energy convergence threshold of 10^{-4} Ry was employed in the iteration process. The comparison of the GGA-PBE function employed in CASTEP and WIEN2k was conducted comprehensively in this study.

Moreover, to validate the significance of FP-LPAW in conjunction with the mBJ hybrid function, an analysis employing the Heyd-Scuseria-Ernzerhof 2006 functional (HSE06) within the framework of Quantum ESPRESSO (QE) was conducted.⁴² In the process of the scf calculation, a convergence threshold of 60 Ry was established for the E_{cutoff} wave function, and a denser k -mesh of $14 \times 14 \times 14$ in the Brillouin zone was utilized. The phonon dispersion analysis was conducted through the utilization of the phonopy module integrated in the WIEN2k software. Moreover, *ab initio* molecular dynamics (AIMD) simulations were executed using the Forcite tools, wherein the NVE thermodynamic ensemble was designated to assess the thermal stability of the compounds under investigation at room temperature.

3. Results and discussion

3.1 Structural analysis

The investigated alkali-based single halide perovskite compounds, denoted as XMgI_3 ($X = \text{Li/Na}$), exhibit a cubic ABX_3 structure, conforming to the $\text{Pm}\bar{3}\text{m}$ crystallographic space group (no. 221). The cubic primitive unit cell of XMgI_3 (where $X = \text{Li/Na}$) comprises five atoms. Specifically, the X atoms are positioned at the corners in the 1a Wyckoff position (0, 0, 0), the Mg atom occupies the body center in the 1b Wyckoff position (0.5, 0.5, 0.5), and the I atoms are positioned at the face center in the Wyckoff position (0.5, 0.5, 0.0). The optimized bulk crystal structure of XMgI_3 ($X = \text{Li/Na}$) is given in Fig. 1. Table 1 displays the computed the lattice parameters ($a = b = c$), band gap (E_g), cell volume (V), tolerance factor (τ), and formation energy (E_f) values for the investigated compounds. To further confirm the structural stability, specifically the lattice parameters, of the cubic perovskite materials, we performed the optimization utilizing the CASTEP and WIEN2k code tools. The optimized lattice constants for LiMgI_3 and NaMgI_3 were calculated to be 5.8022/5.8297 Å and 5.8207/5.8408 Å utilizing CASTEP and WIEN2k with the corresponding cell volumes of 194.2461/198.0969 Å³ and 195.3316/199.2664 Å³, respectively, as

indicated in Table 1 and Fig. 2A. The lattice parameters increased by approximately 0.47% and 0.34% for LiMgI_3 and NaMgI_3 , respectively, while the volume increased by nearly 2% for both materials. These results indicate that their cubic structures remain stable even when optimized with different tools. Due to ionic differences between the Li and Na atoms, variations in both their lattice constants and cell volume were observed when utilizing the same tool (either CASTEP or WIEN2k).

The Goldschmidt tolerance factor, denoted as “ τ ”, is widely used to investigate the structural stability of ABX_3 perovskites, giving insight to determine the compatibility of the cations within their structure, which is defined as follows:⁴⁴

$$\tau = \frac{r_A + r_X}{\sqrt{2}(r_B + r_X)}, \quad (1)$$

where r_A , r_B , and r_X are the A-site, B-site, and X-site ionic radii, respectively. In general, perovskite structures are stable in cubic structures when their tolerance factor is in the range of $0.8 < \tau < 1$.^{45–48} Alternatively, when $\tau < 0.8$, the perovskite adopts an orthorhombic structure, whereas for $\tau > 1$, it is categorized as having a hexagonal crystal structure.⁴⁹ The ionic radii used in this calculation were 1.13, 1.39, 0.72, and 2.20 Å for Li, Na, Mg, and I, respectively.⁴⁷ Thus, the calculated tolerance factors of 0.81 for LiMgI_3 and 0.87 for NaMgI_3 fall within the acceptable range, as listed in Table 1, resulting in the confirmation of the ideal cubic structural stability of the investigated compounds.

Furthermore, the formation energy (ΔE_f) of the compounds was calculated to confirm their thermodynamic stability at room temperature using eqn (2), as follows:⁵⁰

$$\Delta E_f = \frac{[E_{\text{tot}}(\text{XMgI}_3) - (E_i(\text{X}) - E_i(\text{Mg}) - 3E_i(\text{I}))]}{N}, \quad (2)$$

where $E_{\text{tot}}(\text{XMgI}_3)$ represents the total energy of the XMgI_3 compound, N is the number of atoms, and $E_i(\text{X})$, $E_i(\text{Mg})$, and $E_i(\text{I})$ are the total energy of the individual atoms, including X (where $X = \text{Li}$ and Na), Mg, and I, respectively. It is evident that the obtained negative values of the formation energy in Table 1 indicate the stability of the proposed perovskite compounds under ambient conditions. This information is valuable for experimentalists considering the synthesis of these materials at the laboratory scale. To the best of our knowledge, these materials have not been experimentally reported. Nevertheless,

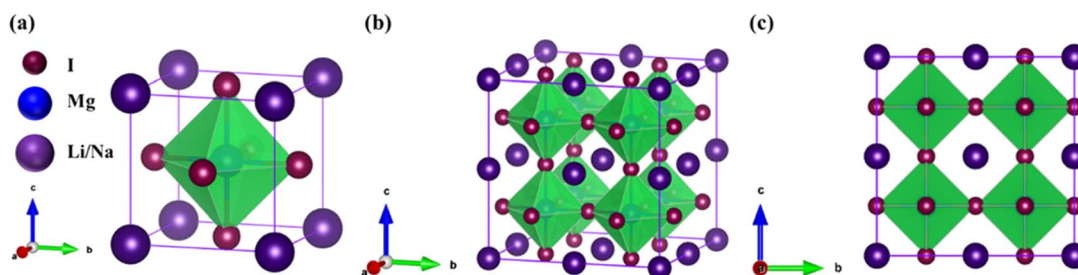


Fig. 1 Optimized crystal structure of XMgI_3 ($X = \text{Li/Mg}$) halide-based single perovskite compounds: (a) 3D unit cell, (b) 3D, and (c) 2D supercell ($2 \times 2 \times 2$). The purple-color ball represents a Li or Na atom, the blue-color ball represents an Mg atom, and the dark-purple color represents an I atom.



Table 1 The computed optimized lattice constants ($a = b = c$), band gap (E_g) using CASTEP, WIEN2k, and QE, cell volume (V), formation of energy (E_f), and tolerance factor (τ) for the cubic structure of XMgI_3 ($X = \text{Li/Na}$) halide single perovskite compounds and some reported data

Compounds	Lattice constants, $a = b = c$ (Å)		E_g (eV)				V (Å ³)			E_f (eV)	τ	Ref.
	CASTEP	WIEN2k	PBE-CASTEP	PBE-WIEN2k	mBJ-WIEN2k	HSE06-QE	CASTEP	WIEN2k	ΔV (%)			
LiMgI ₃	5.8022	5.8297	1.174	1.181	2.474	2.219	194.246	198.097	1.98	−1.8864	0.81	This study
NaMgI ₃	5.8207	5.8408	1.176	1.185	2.556	2.239	195.332	199.266	2.01	−1.9021	0.87	This study
LiMgI ₃	—	5.805	—	1.132	2.586	—	—	—	—	—	—	43
LiCaI ₃	—	6.1382	—	2.457	4.525	—	—	—	—	—	—	43
NaCaI ₃	—	6.146	—	2.527	4.600	—	—	—	—	—	—	43
NaMgCl ₃	—	4.940	—	—	4.16	—	—	—	—	−0.923	—	26
NaBeCl ₃	—	4.550	—	—	4.16	—	—	—	—	−1.023	—	26

the comparable works reported using DFT, focusing on the lattice parameters and band gap, are compiled in Table 1 to validate the credibility of our study.

Furthermore, phonon dispersion calculations offers valuable insights into the dynamical stability of the materials being studied.⁵¹ The phonon dispersion curves were obtained by computing the phonon frequencies along the high symmetry directions ($X \rightarrow \Gamma \rightarrow R \rightarrow M \rightarrow \Gamma$) of the Brillouin zone, as illustrated in Fig. 2B. Typically, stable phonon structures exhibit real frequencies, as denoted by positive signs, whereas unstable structures are characterized by imaginary frequencies, which are indicated by negative signs. The computed phonon spectra revealed that both the LiMgI_3 and NaMgI_3 perovskite materials exhibit real frequencies at the gamma (Γ) point, confirming their dynamic stability. However, at the X-point in the first Brillouin zone, a less negative phonon frequency (~ -0.54 THz) was observed, suggesting localized instabilities or specific vibrational modes affecting certain directions or regions within the crystal lattice.^{52,53} Positive phonon frequencies at the Γ -point

indicate stable vibrational modes at the center of the Brillouin zone, typically corresponding to the collective motions of the entire crystal lattice or large-scale atomic displacements. These stable modes contribute to the overall stability of the material by ensuring well-defined lattice vibrations without leading to global instabilities.

To evaluate the thermal stability of LiMgI_3 and NaMgI_3 , *ab initio* molecular dynamics simulations (AIMD) were carried out at room temperature over a period of 500 ps, utilizing a time step of 1 fs. The results, as depicted in Fig. 2C, reveal that minimal energy fluctuations occurred during the simulation. Furthermore, both perovskite frameworks preserved their original configurations without exhibiting any discernible structural deformities. Thus, these findings undeniably confirm the stability of LiMgI_3 and NaMgI_3 at room temperature.²⁶

3.2 Atomic populations analysis

Mulliken atomic population (MAP) is suitable for gaining insight into the atomic bonding (such as chemical bonds, bond overlap,

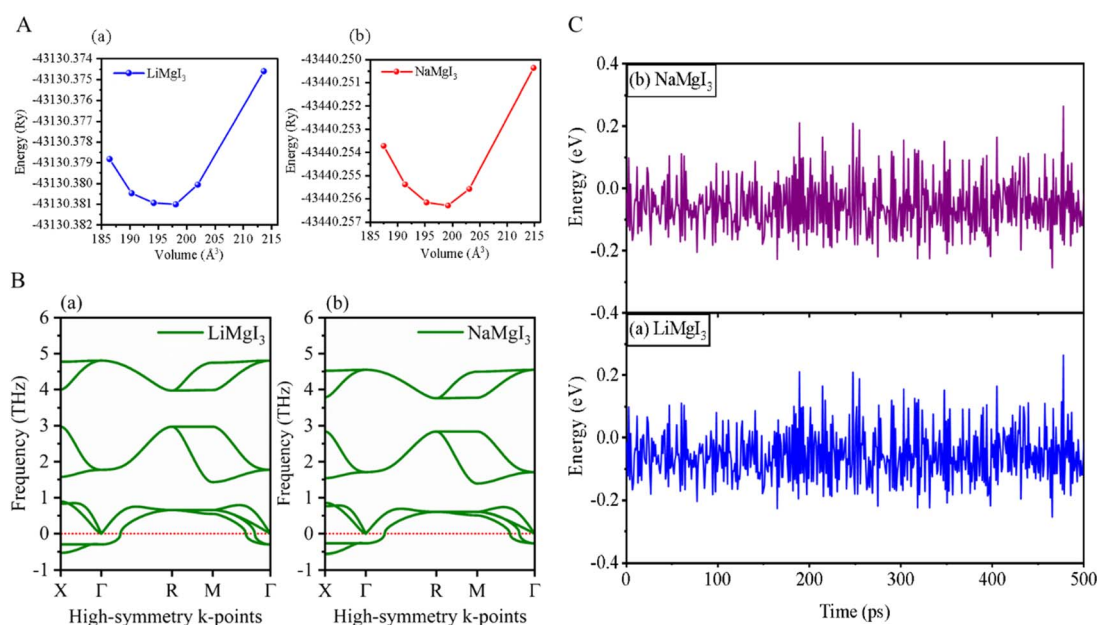


Fig. 2 (A) Total energy with volume optimization curves, (B) phonon dispersion, and (C) thermal stability of LiMgI_3 and the NaMgI_3 , respectively.



Table 2 Charge spilling parameters (%), orbital charge (*e*), atomic Mulliken charge (*e*), Bader charge (*e*), bond population, and bond length for the LiMgI₃ and NaMgI₃ compounds

Compound	Species	Charge spilling (%)	Atom population			Mulliken charge (<i>e</i>)	Bader charge (<i>e</i>)	Bond	Bond population	Bond length (Å)
			s	p	Total					
LiMgI ₃	Li	0.34	2.15	0.00	2.15	+0.850	+0.959	I–Li	0.04	4.095
	Mg		0.67	6.81	7.48	+0.520	+1.488	I–Mg	0.10	2.896
	I		1.88	5.58	7.46	−0.460	−0.816	I–I	−1.84	4.095
NaMgI ₃	Na	0.22	2.18	6.40	8.59	+0.410	+0.928	I–Na	0.04	4.103
	Mg		0.73	6.86	7.58	+0.420	+1.424	I–Mg	0.02	2.901
	I		1.74	5.53	7.28	−0.280	−0.784	I–I	−1.50	4.103

and movement of charge between atoms) in compounds.^{54,55} The calculated bond populations, charges, and bond lengths are summarized in Table 2 for the XMgI₃ (X = Li/Na) compounds. The determined positive (Li, Mg, and Na) and negative (I) charges in the XMgI₃ (X = Li/Na) compounds, as shown in Table 2, suggest that charge is transferred from the alkali metals (Li and Na) and alkaline earth metallic (Mg) atoms to the halogen (I). In both the LiMgI₃ and NaMgI₃ compounds, charge transfer of 0.46 *e* and 0.28 *e* to iodine (I), respectively, was observed. Moreover, we conducted theoretical investigations into the charge-transfer mechanism utilizing Bader analysis,⁵⁶ as depicted in Table 2. The Bader charge analysis utilizes electron density to determine the electronic charges associated with individual atoms.⁵⁷ It helps in understanding the nature of chemical bonding and intermolecular interactions. The ability of the I atom to accept electrons from Li/Na and Mg suggests its ionization nature. Substituting Li with Na resulted in slight alterations in the Bader charges, as shown in Table 2. In the LiMgI₃ structure, the average Bader charge on the I atoms was −0.816 *e*, while that in the NaMgI₃ structure was −0.784 *e*. The variation observed in the charge distribution computed using Mulliken and Bader analyses likely stems from their differing methodologies. Bader analysis emphasizes the topological aspects of electron density, whereas Mulliken analysis relies on population analysis.

Additionally, Table 2 provides data on the bond populations, population ionicity, and bond lengths for the Li–I, Mg–I, Na–I, and I–I bonds within the XMgI₃ (X = Li/Na) perovskite structure. Positive and negative values signify bonding and antibonding states, respectively, with a higher positive bond population denoting increased covalency in the bond.⁵⁸ For example, the lower positive bond population in Li/Na–I (associated with longer bond lengths) and Mg–I (associated with shorter bond lengths) in Table 2 suggests a high level of ionic character and insignificant covalent bonding in both compounds. Additionally, the negative bond population of I–I indicates the formation of antibonding interactions.

3.3 Electron localization function

The electron localization function (ELF) serves as a valuable tool for analyzing the electron distribution and localization during the formation of a crystalline structure.⁵⁹ ELF quantifies the probability of finding electrons with identical spins and fixed positions within a reference electron field, offering insights into the electron localization within the lattice space and revealing

the bonding characteristics in materials. Fig. 3 shows the 3D and 110 crystal dimension ELF maps for the XMgI₃ compounds (X = Li/Na). The right side of the ELF maps illustrates the ELF scaling, including the coordination scaling, where regions with lower electron density are depicted in blue and that with higher electron density in red. The examination of the ELF maps for the XMgI₃ compounds revealed a heightened degree of electron localization around the I ions, which is attributed to their significant electronegativity. This observation is consistent with the findings from the Mulliken population analysis and the Bader charge analysis.

3.4 Elastic constants and mechanical properties

The mechanical and structural stability of materials can be determined by measuring their elastic constant (*C_{ij}*). These measurements indicate that materials deform under stress but return to their original shape once the stress is removed.⁶⁰ Thus, to ensure the materials' mechanical stability, we calculated *C_{ij}* using the finite strain theory, providing insights into their strength and response to external forces. In this investigation, we first performed elastic constant calculations, followed by determining the mechanical and structural stability

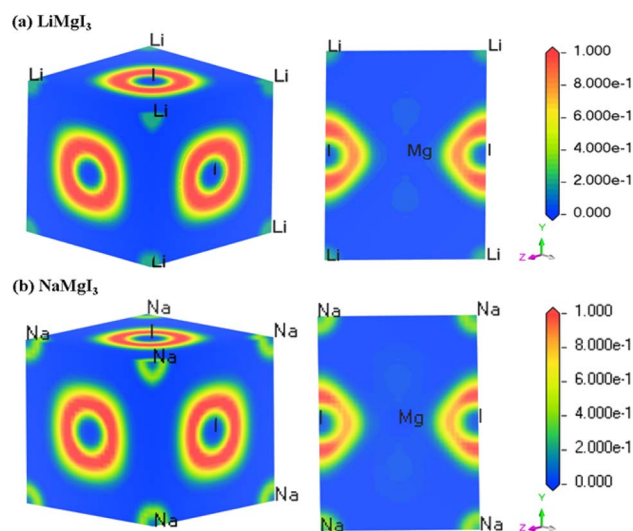


Fig. 3 DFT-computed electron localization function (ELF) in the 3D and 110 crystal direction of (a) LiMgI₃ and (b) NaMgI₃ single perovskite compounds, respectively.



Table 3 The calculated elastic constant C_{ij} (GPa), bulk modulus B (GPa), shear modulus G (GPa), Young's modulus E (GPa), Poisson's ratio (σ), Pugh ratio (B/G), Cauchy pressure ($C_P = C_{12} - C_{44}$) (GPa), anisotropy factor (A), sound velocity (V), Debye temperature θ_D (K), and melting temperature T_m (K) of XMgI_3 ($X = \text{Li/Na}$) single perovskite compounds

Material property	LiMgI_3	NaMgI_3
C_{11} (GPa)	43.10	43.38
C_{12} (GPa)	16.06	15.93
C_{44} (GPa)	10.97	11.53
Bulk modulus, B (GPa)	25.08	25.08
Shear modulus, G (GPa)	11.93	12.36
Young's modulus, E (GPa)	30.88	31.85
Poisson's ratio, σ	0.29	0.29
Pugh ratio, B/G	2.10	2.03
Cauchy pressure, C_P (GPa)	5.09	4.40
Anisotropy factor (A)	0.81	0.84
Transverse sound velocity, v_t (m s^{-1})	1839.41	1843.22
Longitudinal sound velocity, v_l (m s^{-1})	3409.56	3379.92
Average sound velocity, v_m (m s^{-1})	2051.79	2053.93
Debye temperature, θ_D (K)	180.37	180.22
Melting temperature, T_m (K)	807.72	809.38

parameters, as listed in Table 3. The mechanical properties of these materials include hardness, softness, compressibility, ductility, brittleness, and strength, which are vital for industrial applications. In cubical crystals, there are three independent elastic constants, C_{11} , C_{12} , and C_{44} ,⁶¹ which were calculated using the finite strain theory.⁶² According to the symmetry results, $C_{11} = C_{22} = C_{33}$, $C_{12} = C_{23} = C_{13}$, and $C_{44} = C_{55} = C_{66}$.⁶³ Alternatively, it is feasible to determine the Young's modulus (E), shear modulus (G), bulk modulus (B), anisotropy modulus (A), and Poisson's ratio (σ) using the elastic constants.^{64–66} In addition, the elastic constant is used to determine the mechanical stability of the compounds according to the Born stability criterion,⁶⁷ where the crystal deformations in a compound depends on a specific criterion.⁶⁸ In the case of the cubic phase, three independent elastic constants are required to fulfill the Born stability criterion, as given in eqn (3), to determine the stability of a compound:⁶⁹

$$C_{11} > 0, C_{44} > 0, C_{11} - C_{12}, C_{11} - 2C_{12} > 0 \quad (3)$$

The elasticity of length and shape is related to the C_{11} and C_{12} constants, respectively. For a cubic structure, C_{11} must be considerably larger than C_{12} .⁶¹ Interestingly, the estimated elastic constants for both the LiMgI_3 and NaMgI_3 compounds listed in Table 3 confirm they satisfy the Born stability criteria, indicating their mechanical stability. The Pugh ratio (B/G) and Cauchy pressure are useful parameters to assess a material's brittleness and ductility.⁶⁰ In this case, a material is determined to be ductile when B/G is equal to or greater than 1.75, whereas when it is less than 1.75, the material is brittle.⁷⁰ According to this study, the (B/G) ratios for LiMgI_3 (2.1) and NaMgI_3 (2.03) are higher than 1.75, suggesting that these materials exhibit ductile behavior, as shown in Table 3.

The Cauchy pressure for the cubic LiMgI_3 and NaMgI_3 determines their ductility and brittleness based on the negative and positive values of $C_{12} - C_{44}$, as previously reported.⁷¹ A positive value indicates ductility, whereas a negative value suggests brittleness. In this study, the difference between C_{12} and C_{44} (Table 3) for both compounds are positive values, resulting in indicating ductility. Alternatively, the Voigt–Reuss–Hill (VRH) method is an approach used to calculate the B , G , E , and σ of the materials. The Voigt and Reuss methods are used to determine the bulk⁷² and shear⁷³ moduli of materials, respectively, while Hill's⁶⁴ method is used to calculate the average values of these properties. The Reuss bulk modulus (B_R) and Voigt bulk modulus (B_V) are given by eqn (4):

$$B_R = B_V = \frac{C_{11} + 2C_{12}}{3} \quad (4)$$

The shear modulus (G_V) of a material according to Voigt⁷² is presented in eqn (5):

$$G_V = \frac{C_{11} - C_{12} + 3C_{44}}{5} \quad (5)$$

moreover, the shear modulus (G_R) was calculated by Reuss using eqn (6):⁷³

$$G_R = \frac{5C_{44}(C_{11} - C_{12})}{[4C_{44} + 3(C_{11} - 3C_{12})]} \quad (6)$$

and their average value was computed by Hill,⁶⁴ as indicated in eqn (7) and (8), respectively:

$$B = \left(\frac{B_V + B_R}{2} \right) \quad (7)$$

$$G = \left(\frac{G_V + G_R}{2} \right) \quad (8)$$

The values for B , G , and E are presented in Table 3. The B (25.08, 25.08), G (11.93, 12.36), and E (30.88, 31.85) of LiMgI_3 and NaMgI_3 , respectively, indicate that both materials exhibit comparable resistance to changes in volume and shape.

Moreover, the observed E and σ listed in Table 3 can be calculated using the following expression, respectively:⁶⁹

$$E = \frac{9BG}{3B + G} \quad (9)$$

$$\sigma = \frac{3B - 2G}{2(3B + G)} \quad (10)$$

The resistance of a material, which is indicated by its stiffness, is quantified by E , where materials with high E values exhibit increased resistance. Therefore, as shown in Table 3, LiMgI_3 and NaMgI_3 exhibit identical and high E values, suggesting that they possess a significant level of stiffness. Alternatively, σ , which is limited to values between 0.25 and 0.50, determines the behavior of bond forces. A σ value greater than 0.26 indicates that the material is ductile, whereas a value less than 0.26 indicates that it is brittle.⁷⁴ Hence, as indicated in

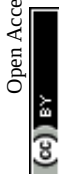


Table 3, the bond force of the LiMgI₃ and NaMgI₃ compounds is close to the center of the above-mentioned range (0.29). As a result, both compounds exhibit a characteristic of ductility that agrees well with the results of the *B/G* ratio and Cauchy's pressure equation.

Moreover, the elastic anisotropy factor (*A*), which is used to determine the direction-dependent properties of a system, was computed by using eqn (11):⁶⁹

$$A = \frac{2C_{44}}{C_{11} - C_{12}} \quad (11)$$

For isotropic compounds, *A* is ideally 1, indicating uniformity, whereas any deviation from 1 indicates the presence of anisotropy.^{75,76} As shown in Table 3, the computed anisotropy factors for both compounds deviated from unity (0.81 for LiMgI₃ and 0.84 for NaMgI₃), indicating the presence of anisotropy in these materials.

The calculation of *G* and *B* enables the determination of the transverse sound velocity, *v_t* (eqn (12)), and longitudinal sound velocity, *v_l* (eqn (13)), of XMgI₃ (*X* = Li/Na) crystals, where *ρ* refers to the density of the investigated compounds as follows:^{77–80}

$$v_t = \left(\frac{3B + 4G}{3\rho} \right)^{1/2} \quad (12)$$

and

$$v_l = \sqrt{\frac{G}{\rho}} \quad (13)$$

Moreover, utilizing eqn (10) and (11), eqn (12) allows the calculation of the mean sound velocity (*v_m*), as follows:

$$v_m = \left[\frac{1}{3} \left(\frac{2}{v_t^3} + \frac{1}{v_l^3} \right) \right]^{-1/3} \quad (14)$$

The Debye temperature (*θ_D*) is used to determine the thermal characteristics of a material including its melting temperature and thermal expansion. Employing eqn (14), *θ_D* of LiMgI₃ and NaMgI₃ can be obtained, as expressed in eqn (15):

$$\theta_D = \frac{h}{k} \left[\frac{3n}{4\pi} \left(\frac{N_A \rho}{M} \right) \right]^{1/3} \cdot v_m \quad (15)$$

where *h* represents the Planck constant, *k* represents the Boltzmann constant, *N_A* denotes the Avogadro constant, *M* signifies the molecular mass, and *n* indicates the number of atoms in the compound. This calculation yielded valuable insights into the thermal properties of the investigated crystals.

The calculated values (*v_t*, *v_l*, and *v_m*) and *θ_D* for the LiMgI₃ and NaMgI₃ compounds are shown in Table 3. The calculated parameters for LiMgI₃ and NaMgI₃ compounds approximately show similar *θ_D*, making both compounds have similar thermal conductivity and melting temperature. The melting temperature (*T_m*) is a crucial parameter for determining the bond

characteristics and thermal conductivity of XMgI₃ (*X* = Li/Na). The melting temperatures of these cubic materials, as listed in Table 3, were calculated using eqn (16):^{81–83}

$$T_m = 553 + 5.91 C_{11} \quad (16)$$

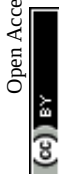
As illustrated in Table 3, both LiMgI₃ and NaMgI₃ exhibit high and comparable melting temperatures (*T_m*), indicating their suitability for high-temperature optoelectronic applications. Thus, the high computed melting temperatures for these compounds imply their strong bonding characteristics and excellent thermal conductivity.

3.5 Electronic properties

In this section, we present the analysis of the energy dispersion and electronic states of the compounds, which determine their electronic properties. The electronic bandgap (*E_g*) of the materials was obtained through band structure analysis, while their partial density of states (PDOS) and total density of states (TDOS) were determined, which describe the distribution of electronics at different energy levels. The electronic properties of the XMgI₃ (*X* = Li/Na) single perovskite materials were investigated using the CASTEP and WIEN2k codes. Fig. 4 and Table 1 demonstrate the narrow indirect band gaps of 1.174/1.176 eV, 1.181/1.185 eV, 2.474/2.556 eV, and 2.219/2.239 eV for LiMgI₃/NaMgI₃, which were calculated employing PBE-CASTEP, PBE-WIEN2k, mBJ-WIEN2k, and HSE06-QE, respectively. It is clear that the standard DFT PBE function consistently underestimated the electronic structure, particularly the band gap, in both CASTEP and WIEN2k, as shown in Fig. 4a and b, respectively. However, despite this underestimation, the results suggest that the proposed compounds exhibit sufficient stability, given that they yielded similar outcomes across different computational codes. Furthermore, the mBJ correlation function (Fig. 4c) accurately predicted the band gap, which correlates well with the experimental values. This suggests that LiMgI₃ and NaMgI₃ have a favorable band gap, which shows their potential for use as semiconductor materials in PV devices and other optoelectronic applications. Further examination was conducted to validate the prediction by the mBJ correlation function employing the alternative robust HSE06 hybrid functional (Fig. 4d), leading to the sustained accurate correlation with the mBJ prediction. The stability and reliability of both LiMgI₃ and NaMgI₃ are evident from the predictions by the mBJ and HSE06 correlation functions, suggesting their suitability for future empirical investigations.

Fig. 4a–d show that both the conduction band minimum (CBM) and valence band maximum (VBM) of the LiMgI₃ and NaMgI₃ compounds are located at *Γ* and *R*, respectively, in the first Brillion zone, which agrees with the previous finding.⁸⁴ The s-block VB metals are flat between the *R* and *M* points, suggesting the presence of heavy holes, whereas the p-block metals have a greater dispersed CB at the *Γ*-point.⁸⁵

Fig. 5 and 6 show the analysis of the partial density of states (PDOS) and total partial density of states (TDOS) of the LiMgI₃ and NaMgI₃ compounds, respectively. In these figures, the TDOS and PDOS were analyzed to identify their effects on the VB



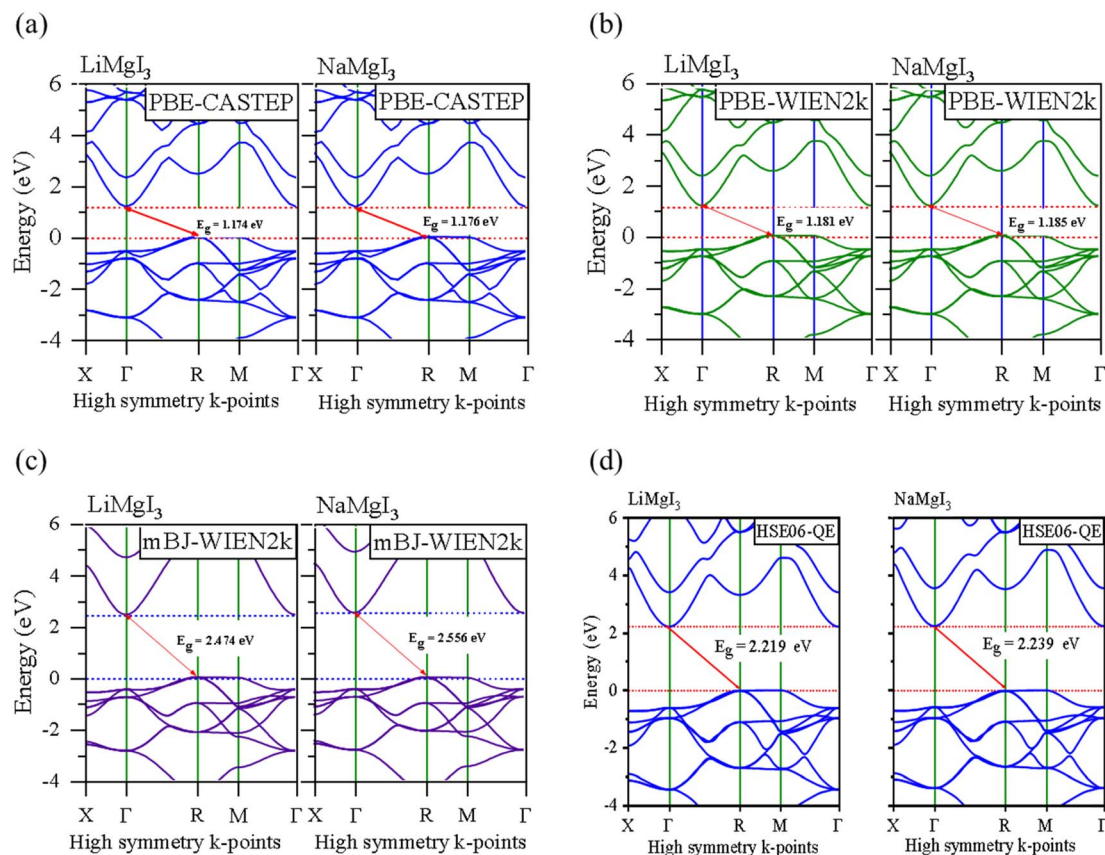


Fig. 4 Band structures computed using (a) GGA-PBE-CASTEP, (b) GGA-PBE-WIEN2k, (c) mBJ-WIEN2k, and (d) HSE06-QE for LiMgI₃ and NaMgI₃, respectively. The Fermi level is set to zero.

to CB electronic characteristics. Fig. 5a illustrates the dominance of the Li p-state in the VB due to its high intensity near to the Fermi level. The proximity of the peak intensity to the Fermi level is crucial for electron transitions from the VB to the CB. Therefore, the Li p-state is the dominant peak in the electron transfer from VB to CB. In the case of the Mg atom, the p-state contributes to the VB, while the s-state contributes to the CB, as depicted in Fig. 5b. Moreover, Fig. 5c clearly shows that the prominent peak near the Fermi level within the VB primarily originates from the I p-state. In summary, the TDOS in Fig. 5d shows that the VB is mainly contributed by the p-states of Li, Mg, and I, while the s-states of Li and Mg contribute to the CB with a smaller contribution from the I p-states in the LiMgI₃ compound.

Notably, when replacing the Li atom with Na, similar trends were observed, as depicted in Fig. 6. These similarities arise from the shared properties of Li and Na as elements within the same family. Our investigation is supported by the previous reports on similar families.^{20,86}

3.6 Optical properties

Details on the optical properties of perovskite compounds can be obtained by calculating various parameters, including the dielectric constant, absorption coefficient, extinction coefficient, refractive index, reflectance, transmission, and loss

function. The expression for the complex dielectric function, $\epsilon(\omega)$, with respect to angular frequency is provided as follows:^{77–80}

$$\epsilon(\omega) = \epsilon_1(\omega) + i\epsilon_2(\omega) \quad (17)$$

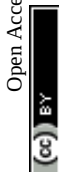
where $\epsilon_1(\omega)$ and $\epsilon_2(\omega)$ represent the real and imaginary components of the complex dielectric function, respectively, and ω is the angular frequency of the incident photon. The absorption coefficient, $\alpha(\omega)$, extinction coefficient, $k(\omega)$, refractive index, $n(\omega)$, reflectivity, $R(\omega)$, conductivity, $\sigma(\omega)$, and loss function, $L(\omega)$, were calculated based on eqn (17), as follows:⁵

$$\alpha(\omega) = \sqrt{2}\omega \left(\sqrt{\epsilon_1^2(\omega) + \epsilon_2^2(\omega)} - \epsilon_1(\omega) \right)^{\frac{1}{2}} \quad (18)$$

$$k(\omega) = \frac{1}{\sqrt{2}} \left(\sqrt{\epsilon_1^2(\omega) + \epsilon_2^2(\omega)} - \epsilon_1(\omega) \right)^{\frac{1}{2}} \quad (19)$$

$$n(\omega) = \frac{1}{\sqrt{2}} \left(\sqrt{\epsilon_1^2(\omega) + \epsilon_2^2(\omega)} + \epsilon_1(\omega) \right)^{\frac{1}{2}} \quad (20)$$

$$R(\omega) = \left| \frac{\sqrt{\epsilon_1(\omega) + i\epsilon_2(\omega)} - 1}{\sqrt{\epsilon_1(\omega) + i\epsilon_2(\omega)} + 1} \right|^2 \quad (21)$$



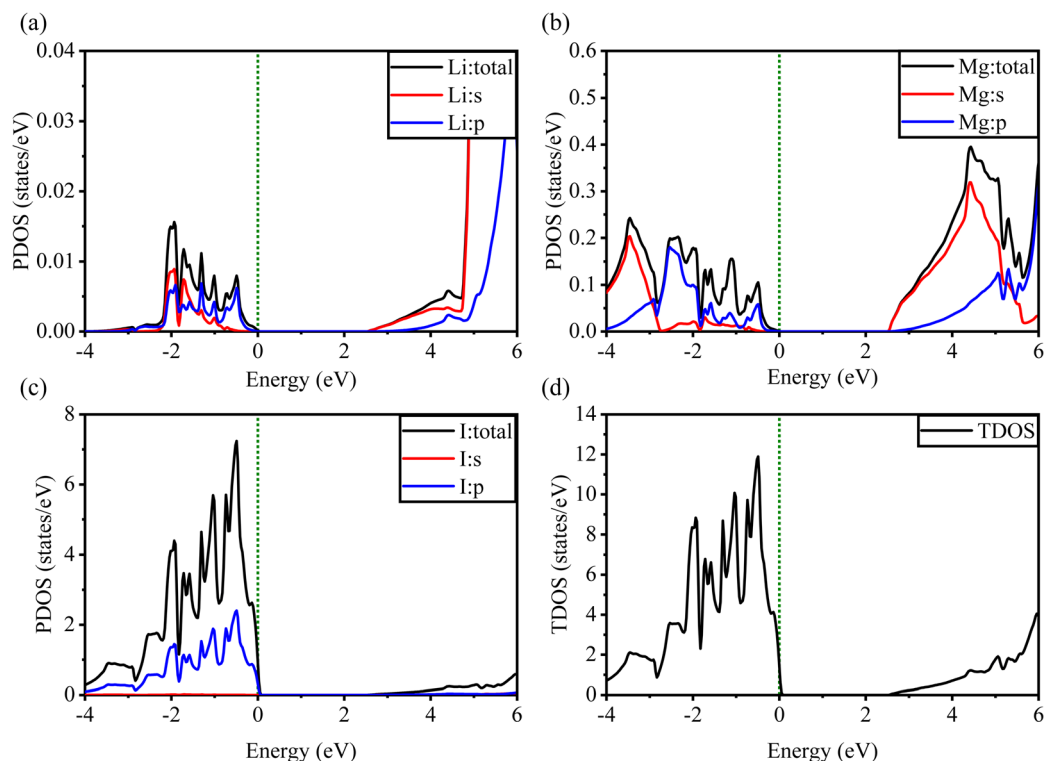


Fig. 5 Calculated PDOS of individual atoms in LiMgI_3 including (a) Li, (b) Mg, and (c) I and (d) TDOS of the LiMgI_3 perovskite compound.

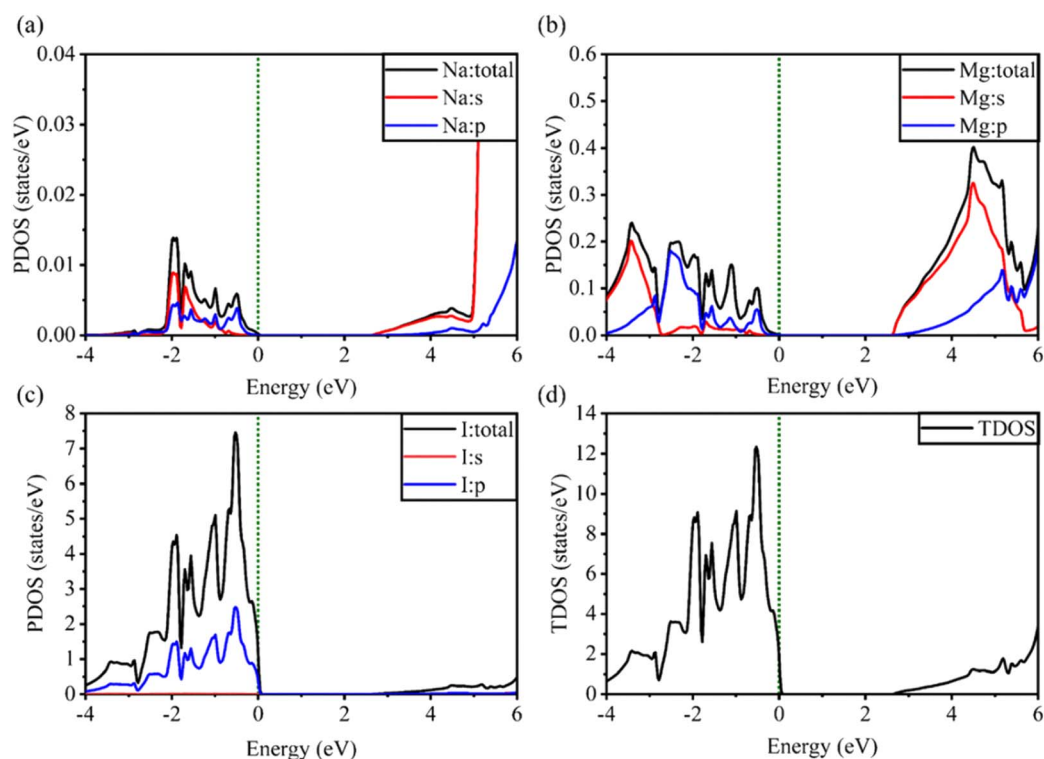


Fig. 6 Calculated PDOS of individual atoms in the NaMgI_3 compound including (a) Na, (b) Mg, and (c) I and (d) TDOS of the NaMgI_3 perovskite structure.



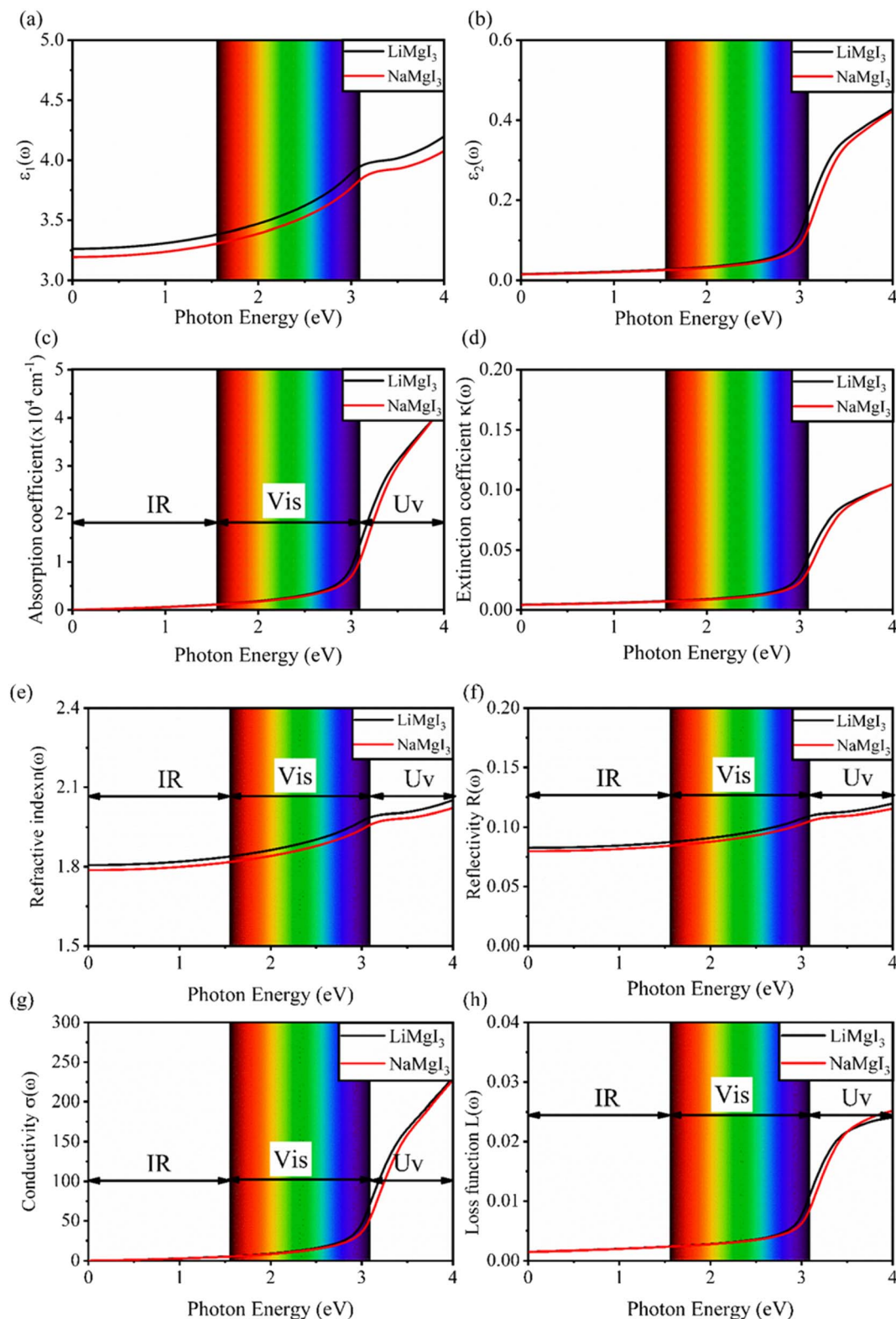


Fig. 7 Calculated optical properties of XMgI_3 ($\text{X} = \text{Li/Na}$) alkaline-based single halide perovskite compounds including the dielectric functions for (a) real part ($\epsilon_1(\omega)$), (b) imaginary part ($\epsilon_2(\omega)$), (c) absorption coefficient ($\alpha(\omega)$), (d) extinction coefficient ($\kappa(\omega)$), (e) index of refraction ($n(\omega)$), (f) reflectivity ($R(\omega)$), (g) conductivity ($\sigma(\omega)$), and (h) loss function ($L(\omega)$).



$$\sigma(\omega) = \frac{\omega \varepsilon_2}{4\pi} \quad (22)$$

and

$$L(\omega) = \frac{\varepsilon_1(\omega)}{\varepsilon_1^2(\omega) + \varepsilon_2^2(\omega)} \quad (23)$$

Fig. 7 shows the optical properties of the investigated LiMgI₃ and NaMgI₃ compounds. Based on the photon radiation on the surface of the compounds, the dielectric function determines their optical properties. Fig. 7a and b show the dielectric functions of the real and imaginary parts of XMgI₃ (X = Li/Na), respectively. As shown in Fig. 7a, according to the static frequency of $\varepsilon_1(0)$, the real dielectric constant is 3.26 for LiMgI₃ and 3.19 for NaMgI₃. The $\varepsilon_1(\omega)$ of LiMgI₃ and NaMgI₃ reached the maximum peak intensities of 3.96 and 3.86 at the 3.10 eV edge of the visible light region, respectively. However, as shown in Fig. 7b, LiMgI₃ and NaMgI₃ revealed 0 eV at $\varepsilon_2(0)$, indicating the absence of dissipated energy. The imaginary part of a dielectric material, $\varepsilon_2(\omega)$, increases until energy dissipation occurs in the photon energy absorption region. Thus, the imaginary parts of a dielectric material reflect the behavior of its absorption coefficient.

Fig. 7c shows the absorption coefficient of the cubic structure of LiMgI₃ and NaMgI₃. In Fig. 7c, it is evident that both the LiMgI₃ and NaMgI₃ compounds initiate photon absorption at 1.3 eV and display a wide absorption peak spanning the infrared (IR) to ultraviolet (UV) region. Therefore, the proposed materials are highly suitable as novel lead-free halide perovskite materials for solar energy harvesting applications. The extinction coefficient demonstrates how the light intensity attenuated on the investigated compounds, LiMgI₃ and NaMgI₃, as displayed in Fig. 7d, where both compounds exhibit similar behavior. Thus, the light-absorbing properties of both compounds are similar and consistent with the discussion in Fig. 7c.

Fig. 7e shows the evaluation of the optical characteristics of the refractive index, which explains the bending or refracting behavior of light in a medium. The static refractive indices of LiMgI₃ and NaMgI₃ were determined to be 1.81 and 1.78, respectively. This suggests that the square of the refractive index ($n(\omega)$)² corresponds to $\varepsilon_1(\omega)$ at a static frequency, as represented in Fig. 7a. Additionally, both compounds reached their maximum at the edge of higher energy of visible light (3.1 eV). The detection of the refractive index peaks within the low-energy segment of the spectrum is a crucial aspect, especially in the visible region, providing valuable insights for applications in optoelectronic devices. Thus, examining the reflectivity of perovskites offers insights into their surface attributes. Fig. 7f illustrates the reflectance spectra of the LiMgI₃ and NaMgI₃ perovskite compounds as a function of photon energy. Both compounds consistently demonstrate low reflectivity (less than 0.10) across the infrared to visible region spectrum, which is negligible. Remarkably, their reflectivity remains consistently low in the visible to infrared range, making these materials well-suited for solar cell applications.

Fig. 7g shows how electromagnetic (EM) radiation induces optical excitation in the compounds, displaying the conductivity $\sigma(\omega)$ of XMgI₃ (X = Li and Na). In the case of LiMgI₃ and NaMgI₃,

their $\sigma(\omega)$ remains zero in the photon energy range of 0 eV to 0.98 eV due to the absence of optical excitation, indicating the absence of interaction between incident EM radiation and the electrons in these materials in this energy range. As LiMgI₃ and NaMgI₃ absorb energy, their electrons shift from the VB to the CB. The consistency of their spectra with the absorption coefficient analysis (Fig. 7c) suggests that absorbing light within the visible part of the electromagnetic spectrum is particularly beneficial for solar cell applications. Another significant consideration involves measuring the energy loss function, denoted as $L(\omega)$, which accounts for inter-band, intra-band, and plasmonic interactions. Additionally, the optical loss serves as an indicator of energy dissipation through scattering, dispersion, and thermal effects, as depicted in Fig. 7h. Fascinatingly, for both LiMgI₃ and NaMgI₃, their optical loss in the visible region (1.55–3.10 eV) is nearly insignificant compared to that in the ultraviolet region (3.10–4.0 eV), confirming the suitability of these materials to realize an excellent optoelectronic performance within the visible range of the electromagnetic spectrum.

4. Conclusion

This investigation explored the structural, electronic, optical, and mechanical attributes of cubic XMgI₃ (X = Li/Na) through first-principle calculations by employing CASTEP and the GGA-PBE exchange-correlation function. Our examination of the elastic constants and mechanical properties indicated the notable stability and ductile nature of each perovskite material. Additionally, we investigated the electron charge distribution using Mulliken atomic population analysis and the electron localization function. The developed compounds exhibited advantageous indirect narrow band gaps (2.474 eV for LiMgI₃ and 2.556 eV for NaMgI₃) and a broad-spectrum absorption coefficient using the mBJ correlation function in WIEN2k. Based on our findings, especially the band gap and optical properties, these alkali-based halide perovskite materials are suitable for several applications, such as photovoltaics, photocatalysts, and optoelectronic devices. DFT analysis suggested their highly favorable band gap for photovoltaic applications. Consequently, further efforts are required for the synthesis and exploration of these alkali-based halide perovskite materials for realistic applications and future advancements.

Data availability

This manuscript has associated data in a data repository. The raw/processed data can be made available with a reasonable request to the corresponding author.

Author contributions

Kefyalew Wagari Guji: conceptualization, methodology, writing-original draft preparation writing-reviewing and editing. Tesfaye Abebe Geleta: conceptualization, methodology, software, writing-reviewing and editing, supervising. Nabil Bouri: methodology, software, writing-reviewing and editing. Victor José



Ramirez Rivera: methodology, conceptualization, software, writing-reviewing.

Conflicts of interest

The authors declare that they have no known competing financial interests.

References

- 1 K. Dedecker and G. Grancini, *Adv. Energy Mater.*, 2020, **10**(31), 2001471.
- 2 I. Hamideddine, H. Jebari, N. Tahiri, O. El Bounagui and H. Ez-Zahraouy, *Int. J. Energy Res.*, 2022, **46**(14), 20755–20765.
- 3 T. A. Geleta and T. Imae, *ACS Appl. Nano Mater.*, 2021, **4**(1), 236–249.
- 4 F. Perera, *Int. J. Environ. Res. Public Health*, 2018, **15**(1), 16.
- 5 S. Bouhmaidi, A. Marjaoui, A. Talbi, M. Zanouni, K. Nouneh and L. Setti, *Comput. Condens. Matter*, 2022, **31**, e00663.
- 6 H. I. Eya and N. Y. Dzade, *ACS Appl. Energy Mater.*, 2023, 5729–5738.
- 7 T. A. Geleta and T. Imae, *Bull. Chem. Soc. Jpn.*, 2020, **93**, 611.
- 8 S. Körbel, M. A. Marques and S. Botti, *J. Mater. Chem. C*, 2016, **4**(15), 3157–3167.
- 9 I. Hamideddine, H. Zitouni, N. Tahiri, O. El Bounagui and H. Ez-Zahraouy, *Appl. Phys. A*, 2021, **127**, 1–7.
- 10 T. A. Geleta, D. Behera, R. Sharma, M. m. Al-Anazy, E. S. Yousef, V. Srivastava and A. J. A. Moayad, *RSC Adv.*, 2024, **14**(6), 4165–4178.
- 11 Q. A. Akkerman, M. Gandini, F. Di Stasio, P. Rastogi, F. Palazon, G. Bertoni, J. M. Ball, M. Prato, A. Petrozza and L. Manna, *Nat. Energy*, 2016, **2**(2), 1–7.
- 12 G. E. Eperon, G. M. Paternò, R. J. Sutton, A. Zampetti, A. A. Haghighirad, F. Cacialli and H. J. Snaith, *J. Mater. Chem. A*, 2015, **3**(39), 19688–19695.
- 13 P. Ramasamy, D.-H. Lim, B. Kim, S.-H. Lee, M.-S. Lee and J.-S. Lee, *Chem. Commun.*, 2016, **52**(10), 2067–2070.
- 14 J.-H. Im, C.-R. Lee, J.-W. Lee, S.-W. Park and N.-G. Park, *Nanoscale*, 2011, **3**(10), 4088–4093.
- 15 E. Mosconi, P. Umari and F. De Angelis, *Phys. Chem. Chem. Phys.*, 2016, **18**(39), 27158–27164.
- 16 Q. Mahmood, U.-e. Hani, T. I. Al-Muhimeed, A. A. AlObaid, B. U. Haq, G. Murtaza, T. H. Flemban and H. Althib, *J. Phys. Chem. Solids*, 2021, **155**, 110117.
- 17 D. Ray, C. Clark, H. Q. Pham, J. Borycz, R. J. Holmes, E. S. Aydil and L. Gagliardi, *J. Phys. Chem. C*, 2018, **122**(14), 7838–7848.
- 18 S. Mitro, M. Saiduzzaman, A. Biswas, A. Sultana and K. M. Hossain, *Mater. Today Commun.*, 2022, **31**, 103532.
- 19 S. Mitro, M. Saiduzzaman, T. I. Asif and K. M. Hossain, *J. Mater. Sci.: Mater. Electron.*, 2022, **33**(17), 13860–13875.
- 20 D. Behera, B. Akila, S. K. Mukherjee, T. A. Geleta, A. Shaker and M. M. Salah, *Crystals*, 2023, **13**(10), 1437.
- 21 M. M. Namisi, R. J. Musembi, W. M. Mulwa and B. O. Aduda, *Comput. Condens. Matter*, 2023, **34**, e00772.
- 22 L.-C. Tang, Y.-C. Chang, J.-Y. Huang, M.-H. Lee and C.-S. Chang, *Jpn. J. Appl. Phys.*, 2009, **48**(11R), 112402.
- 23 S. Idrissi, S. Ziti, H. Labrim and L. Bahmad, *Mater. Sci. Semicond. Process.*, 2021, **122**, 105484.
- 24 M. Husain, N. Rahman, N. Sfina, N. H. Al-Shaalan, S. Alharthi, S. A. Alharthy, M. A. Amin, V. Tirth, R. Khan and M. Sohail, *Opt. Quantum Electron.*, 2023, **55**(10), 920.
- 25 Z. Khan, S. N. Khan, M. Husain, N. Rahman, V. Tirth, M. Elhadi, A. Azzouz-Rached, W. Ullah, M. Uzair and S. Al-Qaisi, *Opt. Quantum Electron.*, 2024, **56**(5), 836.
- 26 A. Jehan, M. Husain, V. Tirth, A. Algahtani, M. Uzair, N. Rahman, A. Khan and S. N. Khan, *RSC Adv.*, 2023, **13**(41), 28395–28406.
- 27 R. Sharma, A. Dey, S. A. Dar and V. Srivastava, *Comput. Theor. Chem.*, 2021, **1204**, 113415.
- 28 Y. Nassah, A. Benmakhlof, L. Hadjeris, T. Helaimia, R. Khenata, A. Bouhemadou, S. Bin Omran, R. Sharma, S. Goumri Said and V. Srivastava, *Bull. Mater. Sci.*, 2023, **46**(2), 55.
- 29 M. Caid, D. Rached, S. Al-Qaisi, Y. Rached and H. Rached, *Solid State Commun.*, 2023, **369**, 115216.
- 30 M. Caid, D. Rached, H. Rached and Y. Rached, *J. Mol. Model.*, 2024, **30**(3), 59.
- 31 S. J. Clark, M. D. Segall, C. J. Pickard, P. J. Hasnip, M. I. J. Probert, K. Refson and M. C. Payne, *Z. Kristallogr. Cryst. Mater.*, 2005, **220**(5–6), 567–570.
- 32 M. D. Segall, P. J. D. Lindan, M. J. a. Probert, C. J. Pickard, P. J. Hasnip, S. J. Clark and M. C. Payne, *J. Phys.: Condens. Matter*, 2002, **14**(11), 2717.
- 33 I. Zeba, M. Ramzan, R. Ahmad, M. Shakil, M. Rizwan, M. Rafique, M. Sarfraz, M. Ajmal and S. S. A. Gillani, *Solid State Commun.*, 2020, **313**, 113907.
- 34 X. Liu and J. Fu, *Vacuum*, 2020, **179**, 109504.
- 35 H. Chen, X. Li, R. Wan, S. Kao-Walter and Y. Lei, *Chem. Phys.*, 2018, **501**, 60–67.
- 36 R. J. Meier, *J. Mol. Struct.: THEOCHEM*, 1999, **467**(1), 79–83.
- 37 P. Wisesa, K. A. McGill and T. Mueller, *Phys. Rev. B*, 2016, **93**(15), 155109.
- 38 P. Blaha, K. Schwarz, G. K. H. Madsen, D. Kvasnicka and J. Luitz, *An Augmented Plane Wave+ Local Orbitals Program for Calculating Crystal Properties*, 2001, 60(1).
- 39 K. Schwarz and P. Blaha, *Comput. Mater. Sci.*, 2003, **28**(2), 259–273.
- 40 M. A. Amin, G. Nazir, Q. Mahmood, J. Alzahrani, N. A. Kattan, A. Mera, H. Mirza, A. Mezni, M. S. Refat and A. A. Gobouri, *J. Mater. Res. Technol.*, 2022, **18**, 4403–4412.
- 41 M. A. Ali, A. A. Alothman, M. Mushab, A. Khan and M. Faizan, *J. Inorg. Organomet. Polym.*, 2023, **33**(11), 3402–3412.
- 42 U. Shahzadi, D. Yang, K. Fatima and F. Wang, *J. Phys. Chem. A*, 2024, 1173–1180.
- 43 N. S. Kaleemullah, M. S. Hussain, V. Ashwin, G. Ajay and M. M. S. Sirajuddeen, *Chem. Phys. Impact*, 2024, 100545.
- 44 W. Rahim, A. Cheng, C. Lyu, T. Shi, Z. Wang, D. O. Scanlon and R. G. Palgrave, *Chem. Mater.*, 2020, **32**(22), 9573–9583.
- 45 M. Talebi and A. Mokhtari, *arXiv*, 2023, preprint, arXiv:230212494, DOI: [10.48550/arXiv.2302.12494](https://doi.org/10.48550/arXiv.2302.12494).



- 46 W. Travis, E. Glover, H. Bronstein, D. Scanlon and R. Palgrave, *Chem. Sci.*, 2016, 7(7), 4548–4556.
- 47 H. Tanaka, T. Oku and N. Ueoka, *Jpn. J. Appl. Phys.*, 2018, 57(8S3), 08RE12.
- 48 M. A. Rahman, F. Mostari, M. Z. Hasan, A. Irfan, M. F. Rahman, M. J. Hosain, S. C. Mouna, I. A. Chowdhury, M. Rasheduzzaman and M. S. H. Choudhury, *Phys. B*, 2023, **669**, 415260.
- 49 H. Louis, C. A. Anyama, U. G. Chukwu, A. A. Ayi and A. S. Adeyinka, *Results Opt.*, 2023, **13**, 100506.
- 50 J. K. Rony, M. Islam, M. Saiduzzaman, K. M. Hossain, S. Alam, A. Biswas, M. H. Mia, S. Ahmad and S. K. Mitro, *J. Mater. Res. Technol.*, 2024, **29**, 897–909.
- 51 N. Xu, Y. Chen, S. Chen, S. Li and W. Zhang, *Int. J. Hydrogen Energy*, 2024, **50**, 114–122.
- 52 R. Padmavathy, A. Amudhavalli, M. Manikandan, R. Rajeswarapalanichamy, K. Iyakutti and A. K. Kushwaha, *J. Electron. Mater.*, 2019, **48**, 1243–1251.
- 53 L.-y. Huang and W. R. L. Lambrecht, *Phys. Rev. B: Condens. Matter Mater. Phys.*, 2014, **90**(19), 195201.
- 54 R. S. Mulliken, *J. Chem. Phys.*, 1955, **23**(10), 1833–1840.
- 55 M. Segall, R. Shah, C. J. Pickard and M. Payne, *Phys. Rev. B: Condens. Matter Mater. Phys.*, 1996, **54**(23), 16317.
- 56 T. Watcharatharapong, M. Minakshi Sundaram, S. Chakraborty, D. Li, G. M. Shafiullah, R. D. Aughterson and R. Ahuja, *ACS Appl. Mater. Interfaces*, 2017, **9**(21), 17977–17991.
- 57 W. Tang, E. Sanville and G. Henkelman, *J. Phys.: Condens. Matter*, 2009, **21**(8), 084204.
- 58 F. M. Hossain, B. Z. Dlugogorski, E. M. Kennedy, I. V. Belova and G. E. Murch, *Solid State Commun.*, 2010, **150**(17–18), 848–851.
- 59 K. Artmann, *Z. Naturforsch. A*, 1946, **1**(8), 426–432.
- 60 M. Khan, M. Z. Rahaman and M. L. Ali, *ACS Omega*, 2023, **8**(28), 24942–24951.
- 61 M. Jamal, S. J. Asadabadi, I. Ahmad and H. R. Aliabad, *Comput. Mater. Sci.*, 2014, **95**, 592–599.
- 62 F. D. Murnaghan, *Am. J. Math.*, 1937, **59**(2), 235–260.
- 63 R. Majumder, S. K. Mitro and B. Bairagi, *J. Alloys Compd.*, 2020, **836**, 155395.
- 64 R. Hill, *Proc. Phys. Soc., London, Sect. A*, 1952, **65**(5), 349.
- 65 X. Tao, J. Yang, L. Xi and Y. Ouyang, *J. Solid State Chem.*, 2012, **194**, 179–187.
- 66 P. Mao, B. Yu, Z. Liu, F. Wang and Y. Ju, *J. Appl. Phys.*, 2015, **117**(11), 115903.
- 67 F. Mouhat and F.-X. Coudert, *Phys. Rev. B: Condens. Matter Mater. Phys.*, 2014, **90**(22), 224104.
- 68 On the stability of crystal lattices. I, *Mathematical Proceedings of the Cambridge Philosophical Society*, ed. M. Born, Cambridge University Press, 1940.
- 69 S. A. Dar, S. A. Khandy, I. Islam, D. C. Gupta, U. K. Sakalle, V. Srivastava and K. Parrey, *Chin. J. Phys.*, 2017, **55**(5), 1769–1779.
- 70 S. Pugh, *London, Edinburgh Dublin Philos. Mag. J. Sci.*, 1954, **45**(367), 823–843.
- 71 M. I. Kholil and M. T. H. Bhuiyan, *J. Phys. Chem. Solids*, 2021, **154**, 110083.
- 72 Q.-J. Liu, H. Qin, Z. Jiao, F.-S. Liu and Z.-T. Liu, *Mater. Chem. Phys.*, 2016, **180**, 75–81.
- 73 S. Kuma and M. M. Woldemariam, *Adv. Condens. Matter Phys.*, 2019, **2019**, 1–12.
- 74 E. D. Bauer, F. Ronning, B. L. Scott and J. D. Thompson, *Phys. Rev. B: Condens. Matter Mater. Phys.*, 2008, **78**(17), 172504.
- 75 H. Y. Wu, Y. H. Chen, C. R. Deng, X. Y. Han and Z. J. Liu, *J. Solid State Chem.*, 2015, **231**, 1–6.
- 76 Q. Fu, L. Si, J. Liu, H. Shi and Y. Li, *Appl. Opt.*, 2022, **61**(21), 6330–6338.
- 77 A. Settoutf, H. Rached, N. Benkhetto and D. Rached, *Comput. Condens. Matter*, 2019, **19**, e00377.
- 78 A. Benslimane, S. Kouidri, H. Rached, M. El Keurti, S. Meliani and M. Ould Moussa, *Indian J. Phys.*, 2024, **98**(3), 955–966.
- 79 S. Meliani, S. Kouidri, H. Rached, M. El Keurti, M. Ould Moussa and A. Ben Slimane, *Solid State Commun.*, 2022, **357**, 114973.
- 80 T. A. Geleta, D. Behera, N. Bouri, V. J. R. Rivera and F. M. Gonzalo, *J. Comput. Chem.*, 2024, **1**.
- 81 Y. Shen, D. R. Clarke and P. A. Fuierer, *Appl. Phys. Lett.*, 2008, **93**(10), 102907.
- 82 G. Ajay, V. Ashwin, M. M. S. Sirajuddeen and A. Alam, *Phys. B*, 2024, **682**, 415858.
- 83 M. Rahman, M. R. U. Akhand, M. M. Ali, P. Barman, M. F. Rahman, M. Rasheduzzaman, M. M. Hossen, M. S. H. Choudhury, S. Nasrin and M. Z. Hasan, *Phys. B*, 2024, **685**, 415997.
- 84 M. R. Filip and F. Giustino, *J. Phys. Chem. C*, 2016, **120**(1), 166–173.
- 85 D. Ray, C. Clark, H. Q. Pham, J. Borycz, R. J. Holmes, E. S. Aydil and L. Gagliardi, *J. Phys. Chem. C*, 2018, **122**(14), 7838–7848.
- 86 D. Behera, T. A. Geleta, I. Allaoui, M. Khuili, S. K. Mukherjee, B. Akila and S. Al-Qaisi, *Eur. Phys. J. Plus*, 2024, **139**(2), 127.

